



100V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)} max	Ι _D T _C = +25°C
-100V	240mΩ @ V _{GS} = -10V	-9A
-1007	300mΩ @ V _{GS} = -4.5V	-8A

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power management functions
- Analog Switch

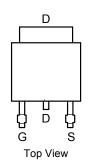
Features

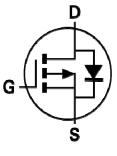
- Low On-Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.33 grams (approximate)







Internal Schematic

Ordering Information (Note 4)

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Г	Part Number	Compliance	Case	Packaging
	DMP10H400SK3-13	Standard	TO252	2,500/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

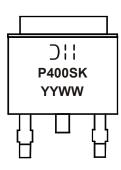
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information

Notes:



>!! = Manufacturer's Marking
P400SK = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 13 = 2013)
WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V _{DSS}	-100	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 4) V _{GS} = -10V	Steady	$T_C = +25^{\circ}C$	I _D	-9	А
	State	T _C = +100°C		-5.5	
Maximum Body Diode Forward Current (Note 4)	I _S	-4	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-15	А		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 4)	T _C = +25°C	Р	42	W
Total Power Dissipation (Note 4)	T _C = +100°C	PD	17	
Thermal Resistance, Junction to Ambient (Note 4)	R _{0JA}	44	°C111	
Thermal Resistance, Junction to Case (Note 4)	R _{0JC}	3	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

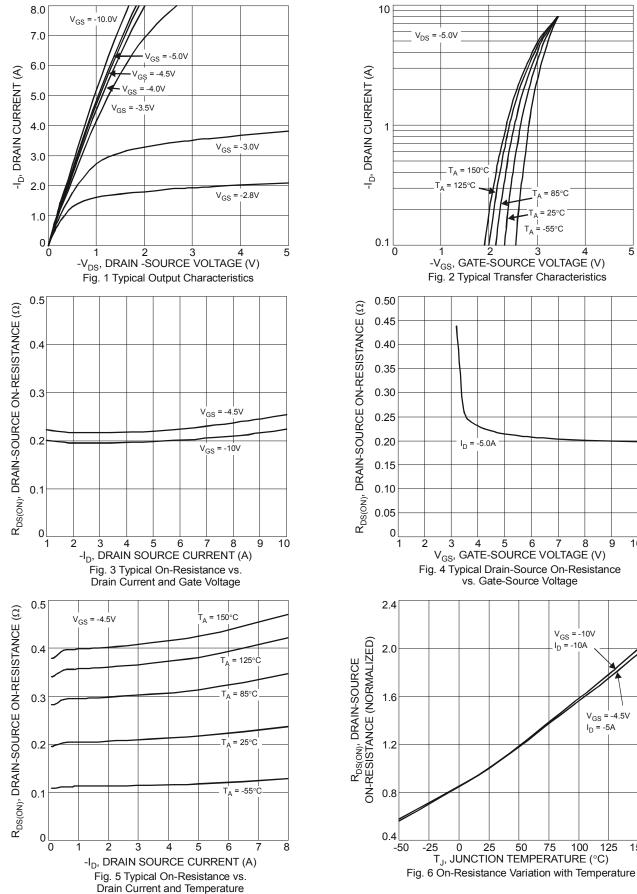
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV _{DSS}	-100		_	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current	I _{DSS}	_		-1	μA	V _{DS} = -80V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V _{GS(th)}	-1		-3	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance			190	240	mΩ	V _{GS} = -10V, I _D = -5A
Static Drain-Source On-Resistance	R _{DS} (ON)	_	210	300	11122	V _{GS} = -4.5V, I _D =-5A
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	V _{GS} = 0V, I _S = -5A
DYNAMIC CHARACTERISTICS (Note 6)						
Input Capacitance	Ciss	_	1239			V _{DS} = -25V, V _{GS} = 0V, f = 1MHz
Output Capacitance	Coss	_	42		pF	
Reverse Transfer Capacitance	Crss	_	28	_		
Gate Resistance	R _G	_	13		Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	8.4	_		
Total Gate Charge (V _{GS} = -10V)	Qg	_	17.5		nC	
Gate-Source Charge	Q _{gs}	_	2.8	_	nc	$V_{\rm DS}$ = -60V, I _D = -5A
Gate-Drain Charge	Q _{gd}		3.2			
Turn-On Delay Time	t _{D(on)}	_	9.1			
Turn-On Rise Time	tr		14.9			V_{DD} = -50V, R_{G} = 9.1 Ω , I_{D} = -5A
Turn-Off Delay Time	t _{D(off)}	_	57.4		ns	
Turn-Off Fall Time	tf	_	34.4		1	
Body Diode Reverse Recovery Time	t _{rr}		25.2		ns	$V_{GS} = 0V, I_S = -5A, dI/dt = 100A/\mu s$
Body Diode Reverse Recovery Charge	Q _{rr}		24.5		nC	$V_{GS} = 0V, I_S = -5A, dI/dt = 100A/\mu s$

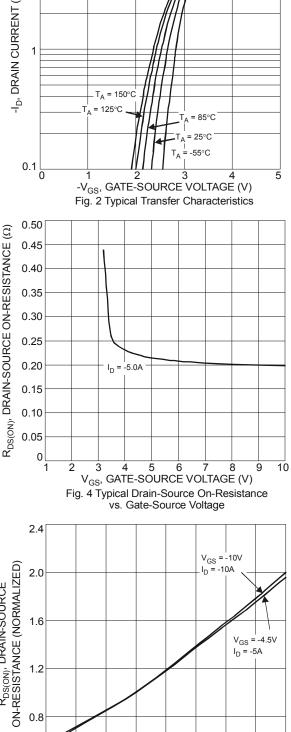
4. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout Notes:

Short duration pulse test used to minimize self-heating effect
 Guaranteed by design; not subject to production testing



DMP10H400SK3



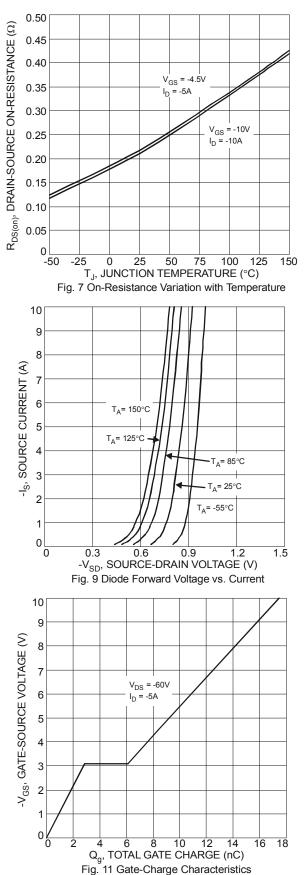


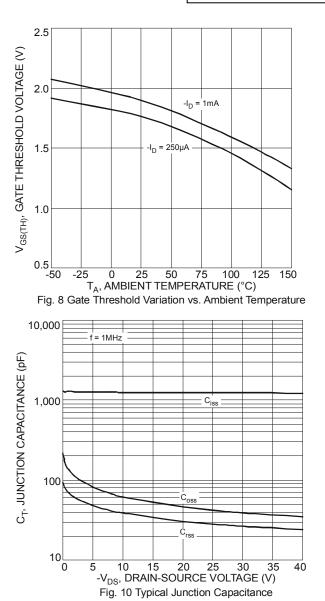
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125

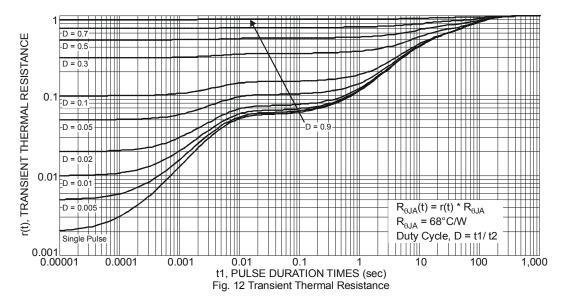






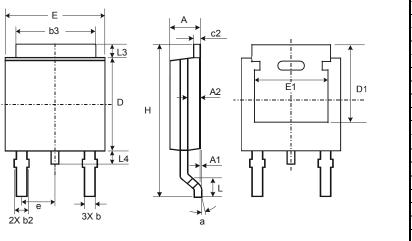






Package Outline Dimensions

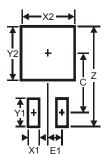
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



TO252						
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
c2	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
Е	6.45	6.70	6.58			
E1	4.32	_	-			
Н	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3



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